

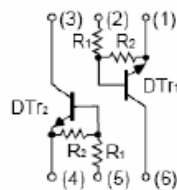
Digital transistors (built-in resistors)

EMH11 General purpose transistor (dual transistors)

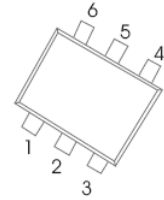
FEATURES

- Two DTC114E chips in a package
- Mounting possible with SOT-563 automatic mounting machines
- Transistor elements are independent, eliminating interference
- Mounting cost and area be cut in half

Marking: H11



SOT-563



Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Value	Unit
Supply voltage	V_{CC}	50	V
Input voltage	V_{IN}	-10~40	V
Output current	I_O	50	mA
	$I_{C(MAX)}$	100	
Power dissipation	P_d	150	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55~+150	°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	0.5			V	$V_{CC}=5V, I_O=100\mu A$
	$V_{I(on)}$			3		$V_O=0.3V, I_O=10mA$
Output voltage	$V_{O(on)}$			0.3	V	$I_O/I_I=10mA/0.5mA$
Input current	I_I			0.88	mA	$V_I=5V$
Output current	$I_{O(off)}$			0.5	μA	$V_{CC}=50V, V_I=0$
DC current gain	G_I	30				$V_O=5V, I_O=5mA$
Input resistance	R_1	7	10	13	k Ω	-
Resistance ratio	R_2/R_1	0.8	1	1.2		-
Transition frequency	f_T		250		MHz	$V_{CE}=10V, I_O=5mA, f=100MHz$